



KBU8A - KBU8M

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Features

- High surge current capability.
- Reliable construction technique.
- Ideal for printed circuit board.



Bridge Rectifiers

Absolute Maximum Ratings*

$T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value							Units
		8A	8B	8D	8G	8J	8K	8M	
V_{RRM}	Maximum Repetitive Reverse Voltage	50	100	200	400	600	800	1000	V
V_{RMS}	Maximum RMS Bridge Input Voltage	35	70	140	280	420	560	700	V
V_R	DC Reverse Voltage (Rated V_R)	50	100	200	400	600	800	1000	V
$I_{F(AV)}$	Average Rectified Forward Current, @ $T_A = 50^\circ\text{C}$	8.0							A
I_{FSM}	Non-repetitive Peak Forward Surge Current	300							A
T_{stg}	Storage Temperature Range	-55 to +150							$^\circ\text{C}$
T_J	Operating Junction Temperature	-55 to +150							$^\circ\text{C}$

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

Symbol	Parameter	Value	Units
P_D	Power Dissipation	6.9	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient,* per leg	18	$^\circ\text{C/W}$
$R_{\theta JL}$	Thermal Resistance, Junction to Lead,* per leg	3.0	$^\circ\text{C/W}$

*Device mounted on PCB with 0.375" (9.5 mm) lead length and 0.5 x 0.5" (13 x 13 mm) copper pads.

Electrical Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Device	Units
V_F	Forward Voltage, per bridge @ 8.0 A	1.0	V
I_R	Reverse Current, total bridge @ rated V_R $T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$	10 500	μA μA

Typical Characteristics

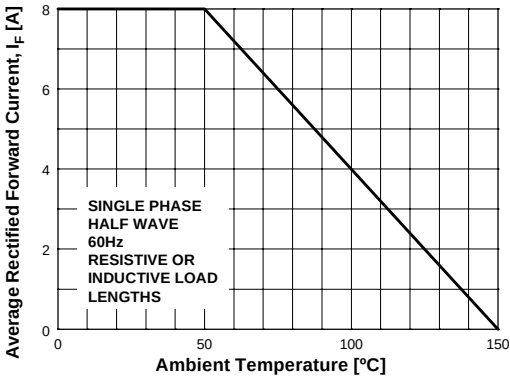


Figure 1. Forward Current Derating Curve

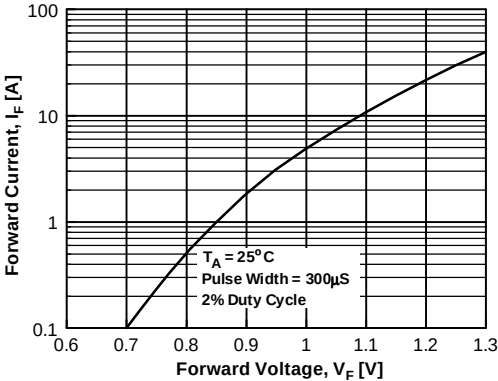


Figure 2. Forward Voltage Characteristics

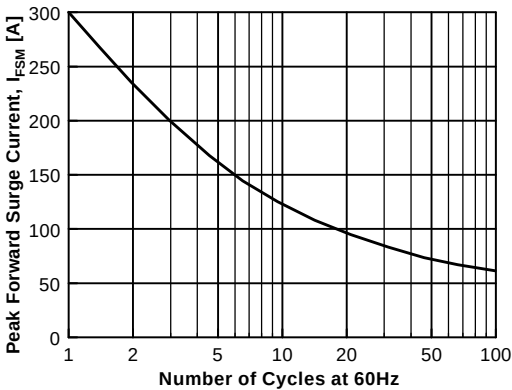


Figure 3. Non-Repetitive Surge Current

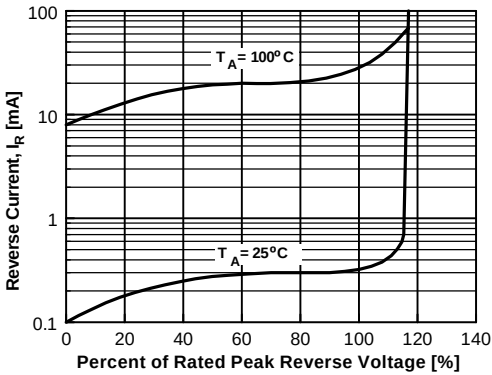


Figure 4. Reverse Current vs Reverse Voltage